<u>10/042924</u> <u>PATENT</u>

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Leonard Forbes

Examiner: W.C. Vesperman

Serial No.:

10/042924

Group Art Unit: 2813

Filed:

January 9, 2002

Docket: 303.684US2

Title:

P-CHANNEL DYNAMIC FLASH MEMORY CELLS WITH ULTRATHIN

TUNNEL OXIDES

COMMUNICATION CONCERNING RELATED APPLICATION(S)

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Applicant would like to bring to the Examiner's attention the following related application(s) in the above-identified patent application:

Serial/Patent No. 09/515630 6639835	Filing Date February 29, 2000	Attorney Docket 303.680US1	Title STATIC NVRAM WITH ULTRA THIN TUNNEL OXIDES
09/945398 6730960	August 30, 2001	303.680US2	STATIC NVRAM WITH ULTRA THIN TUNNEL OXIDES

Respectfully submitted,

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